

mode is confined in the SiO₂ cladding and consequently the thermal performance is expected to be very similar to a pure SiO₂ buried waveguide.

Figure 5(b) shows the central wavelength as the temperature varies. And the slope is about $\Delta\lambda/\Delta T = 0.011 \text{ nm}/^\circ\text{C}$, which is very close to that of an AWG based on pure SiO₂ buried waveguides as expected.

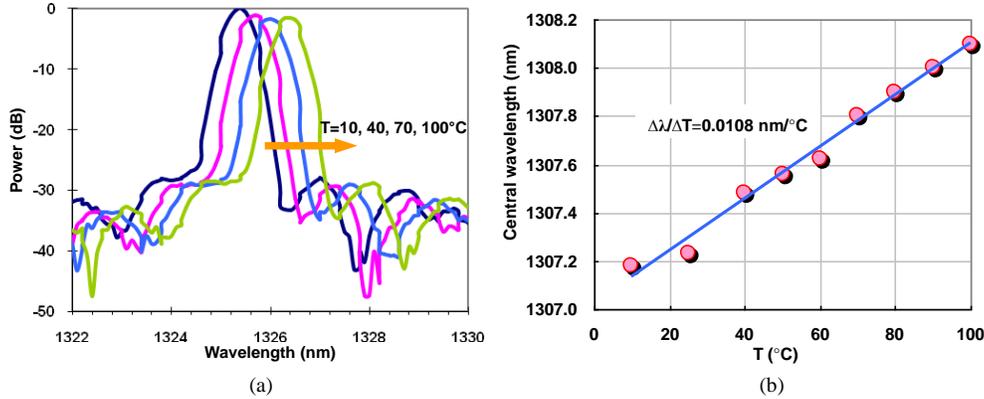


Fig. 5. (a). The spectral response of channel #9 as the temperature varies; (b) the central wavelength of channel #9 as the temperature increases from 10 to 100°C.

3. Conclusions

In this paper, we have demonstrated a low-loss, low-crosstalk AWG (de)multiplexer by using Si₃N₄ buried optical waveguides. The presented AWG (de)multiplexer has 16 channels and the channel spacing is 200GHz (i.e., 1.6nm). The singlemode Si₃N₄ optical waveguide used here has a 5.5 $\mu\text{m} \times 50\text{nm}$ Si₃N₄ core and a 15 μm -thick SiO₂ cladding. With such a structure, the Si₃N₄ optical waveguide has a very low scattering loss due to small mode overlap with the sidewall roughness. For the design of an AWG (de)multiplexer, we have chosen a small gap (about 1 μm -wide) between adjacent arrayed waveguides to reduce the transition loss between the FPR and the arrayed waveguides. The fabricated AWG (de)multiplexer has been characterized in two wavelength ranges around 1310nm, and 1550nm, respectively. At the shorter wavelength range, the optical confinement becomes stronger and consequently the crosstalk is lower than that at longer wavelengths. It has shown that the crosstalk of adjacent and non-adjacent channels are about -30dB, and -40dB, respectively, at the wavelength range of 1310nm. The design could be optimized further to improve the AWG performance at longer wavelength by choosing a thicker core (e.g., 100~200nm). Finally we have also characterized the temperature dependence of the fabricated Si₃N₄ AWG (de)multiplexer and the temperature dependence is about 0.011nm/°C, which is close to that of a pure SiO₂ AWG device because most power of the fundamental mode is confined in the SiO₂ cladding.

Acknowledgements

This work was supported by DARPA MTO under the iPhoD contract No: HR0011-09-C-0123. The authors thank Scott Rodgers, Demis John and John Barton for useful discussions. The optical waveguides were fabricated by LioniX BV, Netherlands.